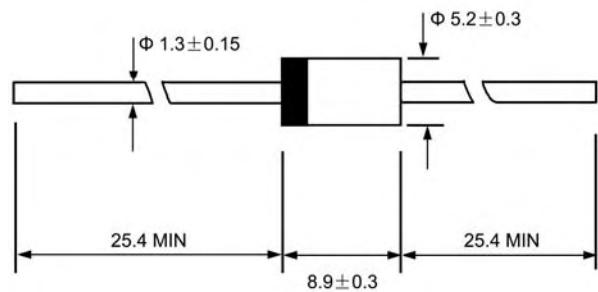


VOLTAGE RANGE: 50 --- 400 V
CURRENT: 5.0 A
DO - 27
Features

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage
- ◇ High current capability
- ◇ Easily cleaned with alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0


Mechanical Data

- ◇ Case: JEDEC DO-27, molded plastic
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.041 ounces, 1.15 grams
- ◇ Mounting position: Any

Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		EGP 50A	EGP 50B	EGP 50C	EGP 50D	EGP 50F	EGP 50G	UNITS		
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	150	200	300	400	V		
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	V		
Maximum DC blocking voltage	V_{DC}	50	100	150	200	300	400	V		
Maximum average forward rectified current 9.5mm lead length @ $T_L=55^\circ\text{C}$	$I_{F(AV)}$	5.0					A			
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	I_{FSM}	150					A			
Maximum instantaneous forward voltage @ 5.0 A	V_F	0.95			1.25		V			
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=125^\circ\text{C}$	I_R	5.0 50			μA					
Maximum reverse recovery time (Note1)	t_{rr}	50					ns			
Typical junction capacitance (Note2)	C_J	95			75		pF			
Typical thermal resistance (Note3)	$R_{\theta JL}$	5.0					$^\circ\text{C}/\text{W}$			
Operating junction temperature range	T_J	- 55 ---- + 150					$^\circ\text{C}$			
Storage temperature range	T_{STG}	- 55 ---- + 150					$^\circ\text{C}$			

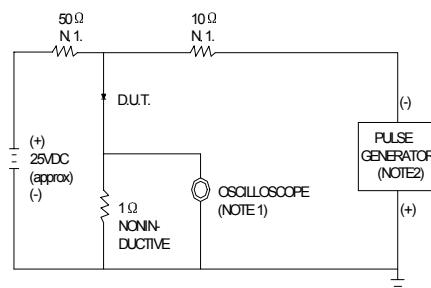
 NOTE: 1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{rr}=0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

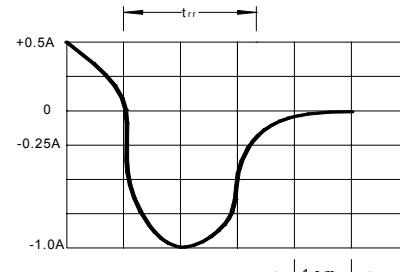
3. Thermal resistance from junction to ambient.

Ratings AND Characteristic Curves

FIG.1 -TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

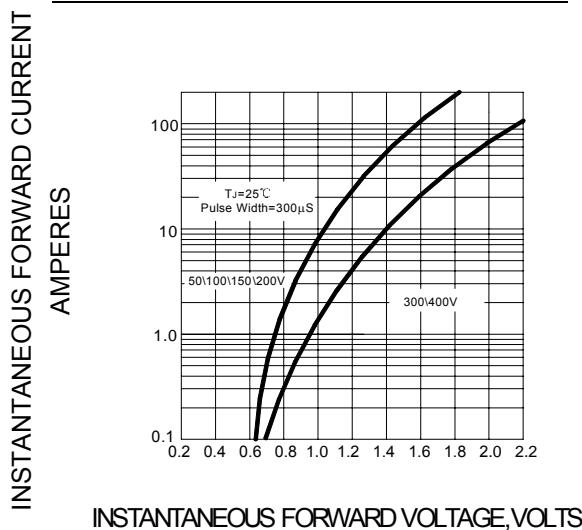


NOTES: 1. RISE TIME=7ns MAX INPUT IMPEDANCE=1MΩ 2.2pF
 2. RISE TIME=10ns MAX SOURCE IMPEDANCE=50Ω



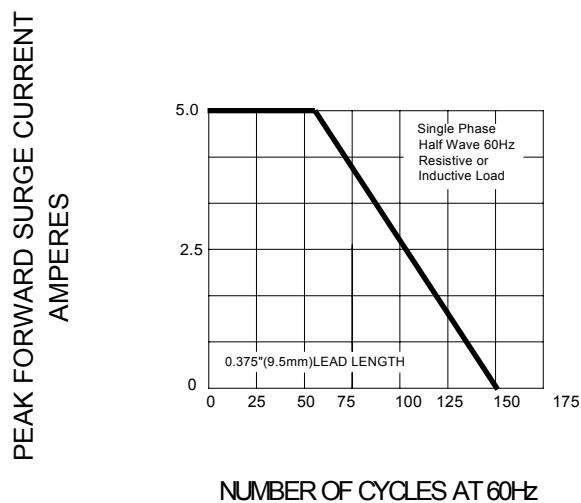
SET TIME BASE FOR 20 ns/cm

FIG.3-TYPICAL FORWARD CHARACTERISTICS



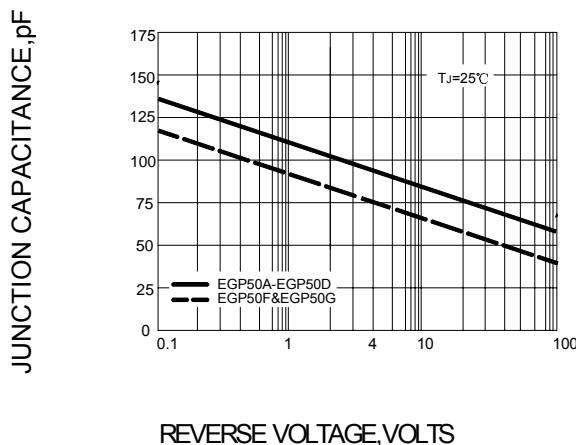
INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.4-TYPICAL REVERSE CHARACTERISTICS



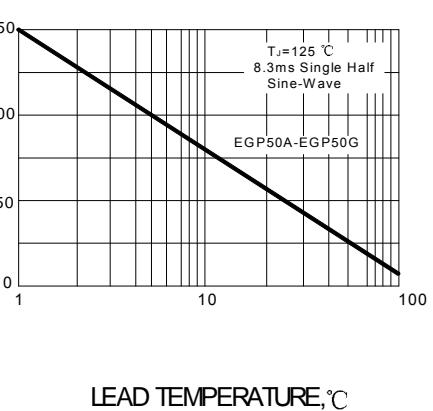
NUMBER OF CYCLES AT 60Hz

FIG.5-TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE, VOLTS

AVERAGE FORWARD CURRENT AMPERES



LEAD TEMPERATURE, °C